NSN 5961-01-011-3523

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-011-3523 **Inclosure Material:** Metal **Overall Length:** Between 0.874 inches and 1.030 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 1.049 inches and 1.062 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 30.0 breakover voltage, dc **Current Rating Per Characteristic:** 1200.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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